

**Products** 

▶ Product Directory

▶ Parametric Search

► Applications

Products | Applications | Design Tools | Ordering | Services & Support | Company

# Power Matters.

Home ▶ 2N3620 (#23114)

# 2N3620 (#23114)

## **Product Status**

Obsolete

### **Related Links**

Technical support How to Buy Available Stock

Sales Contacts

### Overview

Electrical Rating	Symbol	Min	Тур	Max	Unit
Collector to Emitter Saturation Voltage	V <sub>CE(sat)</sub>			1.00	V
DC Current Gain	HFE	3.00			

Maximum Electrical Rating	Symbol	Min	Тур	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	V <sub>BR(CBO)</sub>			75.00	V
Collector Current (dc)	I <sub>C</sub>			2.50	А
Collector-Emitter Voltage (Base Open)	$V_{CEO}$			40.00	V
Emitter-Base Voltage (Collector Open)	V <sub>EBO</sub>			4.00	V
Power Dissipation, Total	P <sub>T</sub>			7.50	W

This part can be found in the following product categories:

▶ Power Discretes & Modules ▶ BJT( BiPolar Junction Transistor) ▶ PNP Transistor

Products | Applications | Company | Careers | Investors | Survey | Privacy Policy | Terms & Conditions | Product Disclaimer | Terms of Use Copyright © 2016 Microsemi Corporation. All rights reserved. The Microsemi logo is a registered trademark of Microsemi Corporation.

Downloaded from Arrow.com.